

NPN Epitaxial Silicon Transistor

KSD882

Recommended Applications

• Audio Frequency Power Amplifier

Features

- Low Speed Switching
- Complement to KSB772

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted) (Note 1)

Symbol	Parameter	Ratings	Units
BV _{CBO}	Collector-Base Voltage	40	V
BV _{CEO}	Collector-Emitter Voltage	30	V
BV _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	3	Α
I _{CP}	Collector Current (Pulse) (Note 2)	7	Α
I _B	Base Current	0.6	Α
P _D	Total Device Dissipation, $T_C = 25^{\circ}C$ $T_A = 25^{\circ}C$	10 1	W
$T_{J_1}T_{STG}$	Junction and Storage Temperature	-55 ~ +150	P ©)

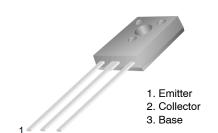
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

THIS DEVICE PLEASEN

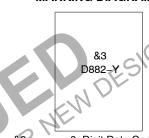
1

2. PW ≤ 10 ms, Duty Cycle ≤ 50%.



TO-126-3LD CASE 340AS

MARKING DIAGRAM



&3	= 3-Digit Date Code
D882	= Specific Device Code
Y	= h _{FE} Grade

ORDERING INFORMATION

Device	Package	Shipping
KSD882YS	TO-126-3 (Pb-Free)	2000 Units / Bulk Bag
KSD882YSTU	TO-126-3 (Pb-Free)	1920 Units / Tube

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Characteristic	Test Condition	Min	Тур.	Max	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 500 \mu A, I_E = 0$	40	_	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 5 \text{ mA}, I_B = 0$	30	_	-	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 500 \mu A, I_C = 0$	5	_	_	V
I _{CBO}	Collector Cut-off Current	V _{CB} = 30 V, I _E = 0	_	_	1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 3 \text{ V}, I_{C} = 0$	_	_	1	μΑ
h _{FE1} h _{FE2}	DC Current Gain (Note 3)	V _{CE} = 2 V, I _C = 20 mA V _{CE} = 2 V, I _C = 1 A	30 60	150 160	400	
V _{CE} (sat)	Collector–Emitter Saturation Voltage (Note 3)	$I_C = 2 \text{ A}, I_B = 0.2 \text{ A}$	-	0.3	0.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage (Note 3)	I _C = 2 A, I _B = 0.2 A	-	1.0	2.0	V
f _T	Current Gain Bandwidth Product	V _{CE} = 5 V, I _E = 0.1 A	_	90	-	MHz
C _{ob}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz		45		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

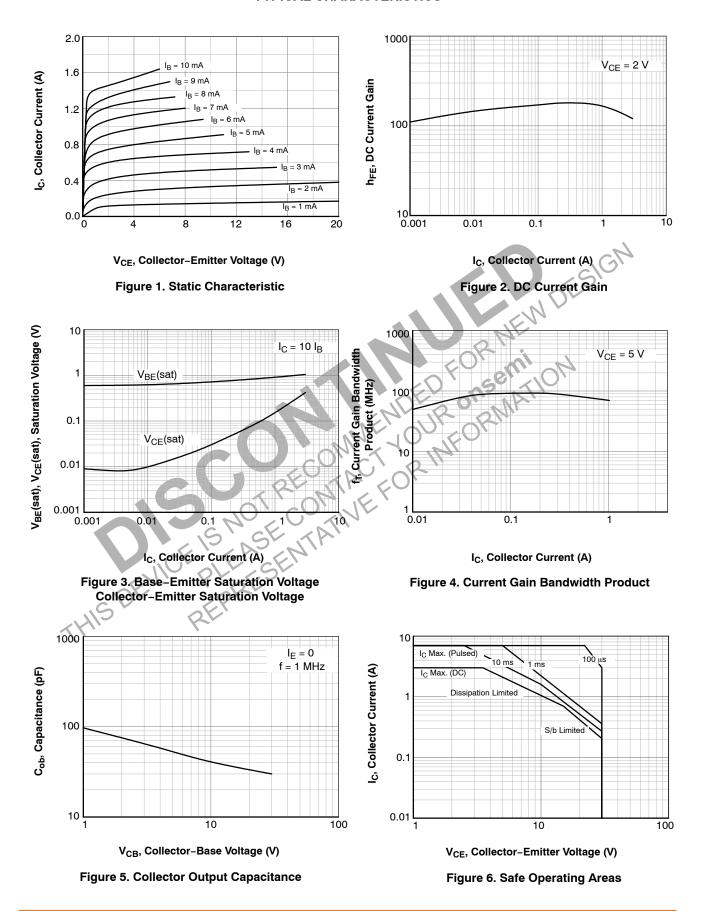
hFE CLASSIFICATION

Classification	R	0	Y-	G
h _{FE2}	60 ~ 120	100 ~ 200	160 ~ 320	200 ~ 400
		OF	ons AT	
		ENL	IR -RMI	
		MILIO	0,50,	
		COMICT	14,	
		CO DO OR	`	
		Br Mili FO		
	101	COLME,		
	JE MOI	COLINE		
	SEIS NOT	COLVE		
	CE IS NOT	ENTATIVE		
OEV	CE IS NOT	ENTATIVE		
OEDEV	CE IS NOTE PLEASE	ENTATIVE		
THIS DEN	CE IS NOT REPRES	100~200		
THIS DEV	CE IS NOT REPRES	ENTATIVE		

^{3.} Pulse Test: PW ≤ 350 μs, Duty Cycle ≤ 2% Pulsed.

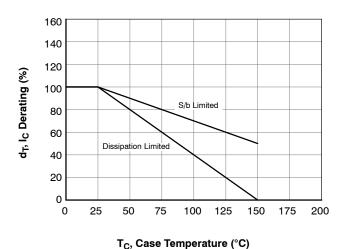
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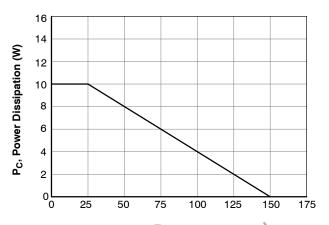
TYPICAL CHARACTERISTICS



KSD882

TYPICAL CHARACTERISTICS (continued)





Power I.

RECONNIENDED FOR INFORMATION

RECONTACTOR INFORMATION

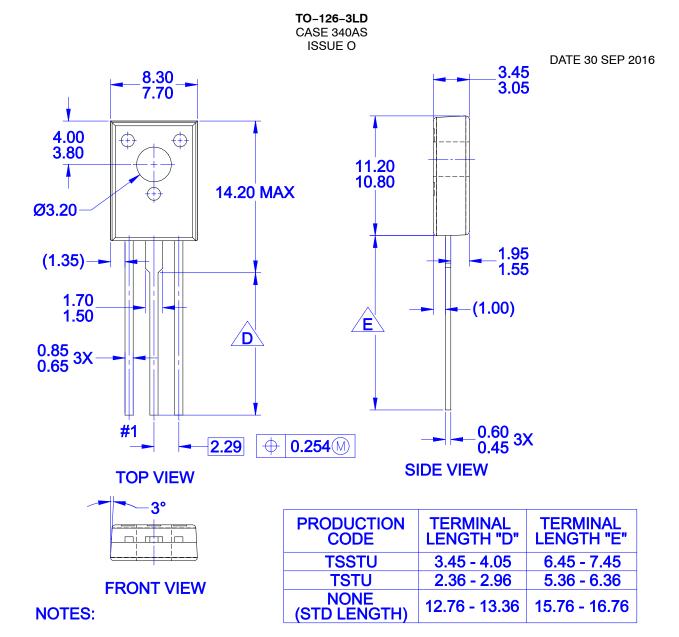
REPRESENTATIVE FOR INFORMATION

REPRESENTATIVE FOR INFORMATION Figure 7. Derating Curve of Safe Operating

Figure 8. Power Derating

T_C, Case Temperature (°C)





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- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR PROTRUSIONS



E FOR TERMINAL LENGTH "E", REFER TO TABLE

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